Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 20 A



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PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 20 A					
V _R	100 V					
V _F at I _F	0.67 V					
I _{RM} max.	11 mA at 125 °C					
T _J max.	175 °C					
E _{AS}	7.50 mJ					
Package	3L TO-220AB					
Circuit configuration	Common cathode					

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS VALUES				
I _{F(AV)}	Rectangular waveform	40	А		
V _{RRM}		100	V		
I _{FSM}	$t_p = 5 \ \mu s$ sine	850	А		
V _F	20 A _{pk} , T _J = 125 °C (per leg)	0.67	V		
TJ	Range	-55 to +175	°C		

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-43CTQ100-M3	UNITS			
Maximum DC reverse voltage	VR	V				
Maximum working peak reverse voltage	V _{RWM}	100	v			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS			
Maximum average forward per leg			20					
current, see fig. 5 per device	I _{F(AV)}	30% duty cycle at $T_{\rm C} = 135\%$	γ cycle at $\Gamma_{\rm C} = 135$ °C, rectangular wavelonn					
Maximum peak one cycle		5 μs sine or 3 μs rect. pulse	Following any rated load condition and	850	A			
non-repetitive surge current per leg, see fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	with rated V _{RRM} applied	275				
Non-repetitive avalanche energy per leg E		$T_J = 25 \text{ °C}, I_{AS} = 0.50 \text{ A}, L = 60 \text{ mH}$		7.50	mJ			
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.50	А			



RoHS COMPLIANT HALOGEN FREE

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		20 A	т ос «о	0.81	V	
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	40 A	T _J = 25 °C	0.98		
See fig. 1	VFM ()	20 A	T _J = 125 °C	0.67		
		40 A	1j = 125 C	0.81		
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	1	mA	
See fig. 2		T _J = 125 °C	VR - Haleu VR	11		
Threshold voltage	V _{F(TO)}			0.71	V	
Forward slope resistance	r _t	$T_J = T_J maximum$		0.43	mΩ	
Maximum junction capacitance per leg	CT	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 °C		1480	pF	
Typical series inductance per leg	L _S	Measured lead to lead 5 m	8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	ge	T _J , T _{Stg}		- 55 to 175	°C		
Maximum thermal resistance junction to case per leg	5	D		2.0			
Maximum thermal resistance junction to case per package	,	R _{thJC}	DC operation	1.0	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.50			
Approvimate weight				2	g		
Approximate weight				0.07	oz.		
Mounting torque	minimum			6 (5)	kgf ⋅ cm		
	maximum			12 (10)	(lbf ⋅ in)		
Marking device			Case style 3L TO-220AB	43CT	Q100		



VS-43CTQ100-M3

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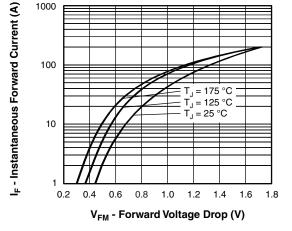


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

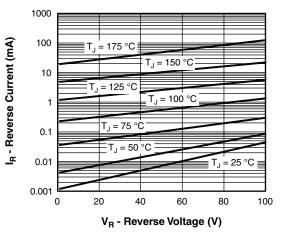


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

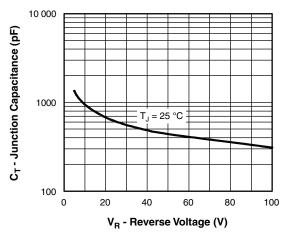
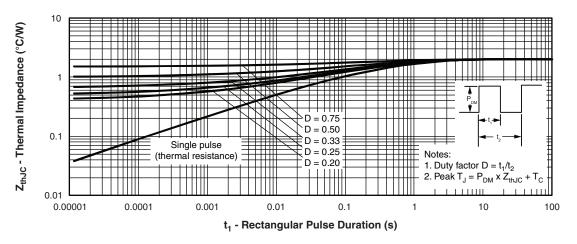


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)





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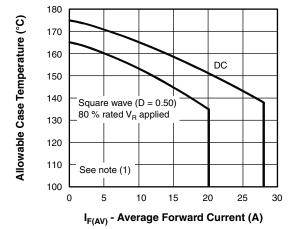
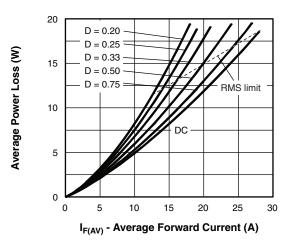
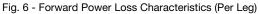


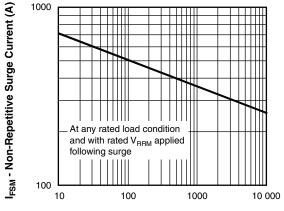
Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)



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t_p - Square Wave Pulse Duration (μs)



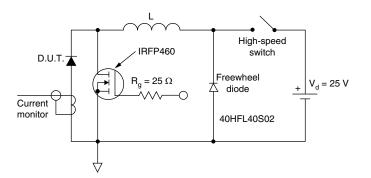


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \, x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \, x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{10} \ \mathsf{V} \end{array}$

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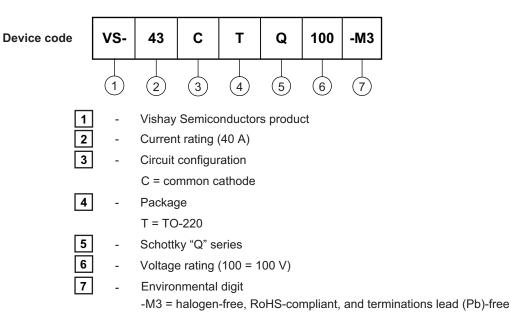
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ORDERING INFORMATION TABLE



ORDERING INFORMATION (Example)								
PREFERRED P/N	PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-43CTQ100-M3	50	1000	Antistatic plastic tube					

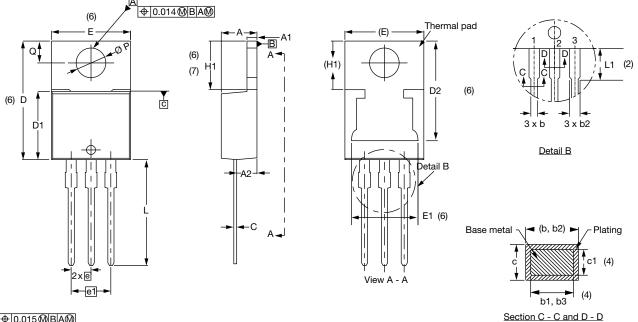
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96154				
Part marking information	www.vishay.com/doc?95028				
SPICE model	www.vishay.com/doc?95065				



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3L TO-220AB

DIMENSIONS in millimeters and inches



⊕0.015@BA@



SYMBOL	MILLIN	IETERS	INC	NOTES	
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.50	2.92	0.098	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.35	0.585	0.604	3
D1	8.38	9.02	0.330	0.355	

Conforms to JEDEC[®] outline TO-220AB

SAMBOI	SYMBOL MILLIMETERS		INC	NOTES	
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	12.88	0.460	0.507	6
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Notes

 $^{(1)}\,$ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only

(5) Controlling dimensions: inches

⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1

⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2 (minimum)

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